# **General Purpose Transistor**

# **PNP Silicon**

#### Features

- Moisture Sensitivity Level: 1
- ESD Rating: Human Body Model: > 4000 V – Machine Model: > 400 V
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

#### MAXIMUM RATINGS

| Rating                       | Symbol           | Value | Unit |
|------------------------------|------------------|-------|------|
| Collector-Emitter Voltage    | V <sub>CEO</sub> | -25   | Vdc  |
| Collector-Base Voltage       | V <sub>CBO</sub> | -25   | Vdc  |
| Emitter-Base Voltage         | V <sub>EBO</sub> | -4    | Vdc  |
| Collector Current–Continuous | Ι <sub>C</sub>   | -200  | mAdc |

#### THERMAL CHARACTERISTICS

| Characteristic  | Symbol                            | Max         | Unit        |
|---|-----------------------------------|-------------|-------------|
| Total Device Dissipation FR–5 Board<br>(Note 1) @T <sub>A</sub> = 25°C<br>Derate above 25°C         | P <sub>D</sub>                    | 225<br>1.8  | mW<br>mW/°C |
| Thermal Resistance, Junction-to-Ambient (Note 1)  | $R_{\theta JA}$                   | 556         | °C/W        |
| Total Device Dissipation Alumina<br>Substrate, (Note 2) @T <sub>A</sub> = 25°C<br>Derate above 25°C | P <sub>D</sub>                    | 300<br>2.4  | mW<br>mW/°C |
| Thermal Resistance, Junction-to-Ambient (Note 2)  | $R_{\theta JA}$                   | 417         | °C/W        |
| Junction and Storage Temperature Range  | T <sub>J</sub> , T <sub>stg</sub> | -55 to +150 | °C          |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

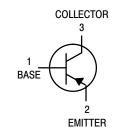
1. FR-5 =  $1.0 \times 0.75 \times 0.062$  in.

2. Alumina = 0.4  $\times$  0.3  $\times$  0.024 in. 99.5% alumina.



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CASE 318 STYLE 6

### MARKING DIAGRAM



C3 = Device Code

M = Date Code\*

= Pb–Free Package

(Note: Microdot may be in either location) \*Date Code orientation and/or overbar may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

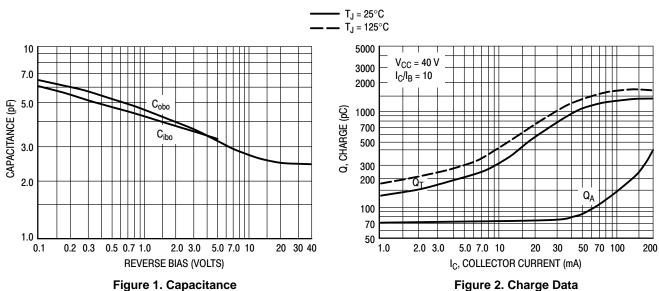
| Device       | Package             | Shipping <sup>†</sup> |
|--------------|---------------------|-----------------------|
| MMBT4126LT1G | SOT-23<br>(Pb-Free) | 3000/Tape & Reel      |

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

| Characteristic  | Symbol                | Min        | Max      | Unit |
|---|-----------------------|------------|----------|------|
| OFF CHARACTERISTICS   |                       |            |          |      |
| Collector – Emitter Breakdown Voltage (Note 3)<br>( $I_C = -1.0 \text{ mAdc}, I_B = 0$ )  | V <sub>(BR)</sub> CEO | -25        | -        | Vdc  |
| Collector–Base Breakdown Voltage $(I_C = -10 \ \mu Adc, I_E = 0)$   | V <sub>(BR)CBO</sub>  | -25        | _        | Vdc  |
| Emitter–Base Breakdown Voltage $(I_E = -10 \ \mu Adc, I_C = 0)$   | V <sub>(BR)EBO</sub>  | -4         | _        | Vdc  |
| Collector Cutoff Current<br>( $V_{CE} = -30$ Vdc, $V_{EB} = -3.0$ Vdc)  | ICEX                  | _          | -50      | nAdc |
| ON CHARACTERISTICS (Note 3)   | •                     |            |          |      |
| DC Current Gain<br>( $I_C = -2.0 \text{ mAdc}, V_{CE} = -1.0 \text{ Vdc}$ )<br>( $I_C = -50 \text{ mAdc}, V_{CE} = -1.0 \text{ Vdc}$ )    | H <sub>FE</sub>       | 120<br>60  | 300<br>- | _    |
| Collector – Emitter Saturation Voltage $(I_C = -50 \text{ mAdc}, I_B = -5.0 \text{ mAdc})$  | V <sub>CE(sat)</sub>  | _          | -0.4     | Vdc  |
| Base – Emitter Saturation Voltage $(I_C = -50 \text{ mAdc}, I_B = -5.0 \text{ mAdc})$   | V <sub>BE(sat)</sub>  | _          | -0.95    | Vdc  |
| SMALL-SIGNAL CHARACTERISTICS  |                       |            |          |      |
| Current-Gain – Bandwidth Product<br>( $I_C = -10$ mAdc, $V_{CE} = -20$ Vdc, f = 100 MHz)  | f <sub>T</sub>        | 250        | _        | MHz  |
| Output Capacitance<br>( $V_{CB} = -5.0 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz}$ )   | C <sub>obo</sub>      | _          | 4.5      | pF   |
| Input Capacitance<br>( $V_{EB} = -0.5 \text{ Vdc}, I_C = 0, f = 1.0 \text{ MHz}$ )  | C <sub>ibo</sub>      | _          | 10       | pF   |
| $      Small - Signal Current Gain \\ (I_C = -2.0 mAdc, V_{CE} = -10 Vdc, f = 1.0 kHz) \\ (I_C = 10 mAdc, V_{CE} = 20 Vdc, f = 100 MHz) $ | h <sub>fe</sub>       | 120<br>2.5 | 480<br>- | _    |
| Noise Figure (I <sub>C</sub> = $-100 \ \mu$ Adc, V <sub>CE</sub> = $-5.0 \ V$ dc, R <sub>S</sub> = $1.0 \ k\Omega$ , f = $1.0 \ kHz$ )    | NF                    | _          | 4.0      | dB   |

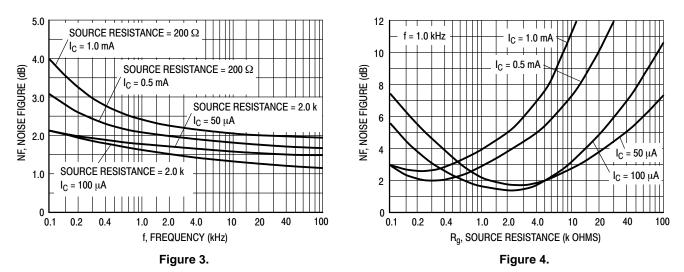
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 3. Pulse Test: Pulse Width  $\leq$  300 µs, Duty Cycle  $\leq$  2.0%.



### **TYPICAL TRANSIENT CHARACTERISTICS**

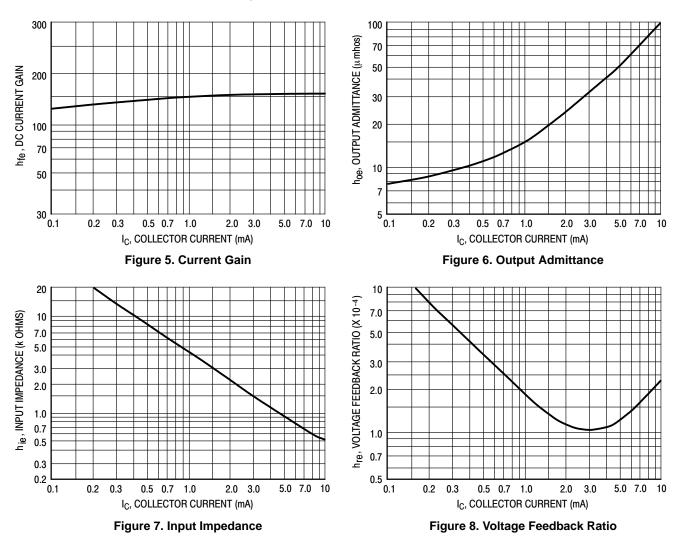
#### TYPICAL AUDIO SMALL-SIGNAL CHARACTERISTICS NOISE FIGURE VARIATIONS

 $(V_{CE} = -5.0 \text{ Vdc}, T_A = 25^{\circ}\text{C}, \text{ Bandwidth} = 1.0 \text{ Hz})$ 

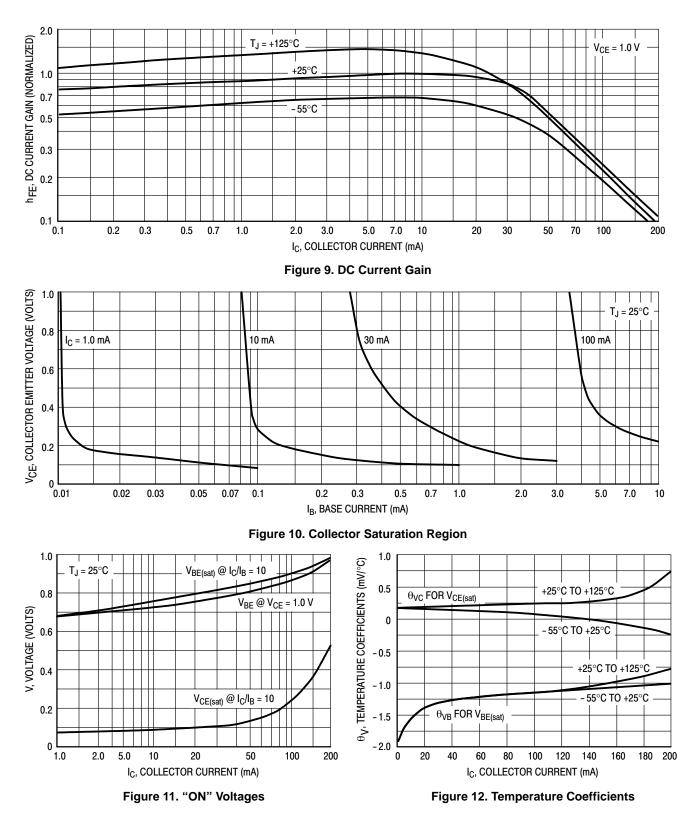


h PARAMETERS

 $(V_{CE} = -10 \text{ Vdc}, f = 1.0 \text{ kHz}, T_A = 25^{\circ}\text{C})$ 



### **TYPICAL STATIC CHARACTERISTICS**







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